LITEON®
OPTOELECTRONICS

LED Display

Product Data Sheet

LTC-5623JG-J

Spec No.: DS30-2008-0093

Effective Date: 05/17/2008

Revision: -

LITE-ON DCC

RELEASE

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LITE-ON Technology Corp. / Optoelectronics
No.90,Chien 1 Road, Chung Ho, New Taipei City 23585, Taiwan, R.O.C.
Tel: 886-2-2222-6181 Fax: 886-2-2221-1948 / 886-2-2221-0660
http://www.liteon.com/opto

LED DISPLAY

LTC-5623JG-J
DATASHEET

Rev	Description	By
01	ORIGINAL (Refer to contour drawing Revision (-))	KITTISAK Apr 28.2008
(Above data for PD and Customer tracking only)		
-	NPPR Received and Upload on OPNC	KITTISAK Apr 30.2008

SPEC. NO.: DS30-2008-0093

D A T E : Apr 30.2008

REV. NO. : -

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FEATURES

∗0.56 inch (14.2 mm) DIGIT HEIGHT.
∗CONTINUOUS UNIFORM SEGMENTS.
∗LOW POWER REQUIREMENT.
∗EXCELLENT CHARACTERS APPEARANCE.
∗HIGH BRIGHTNESS & HIGH CONTRAST.
∗WIDE VIEWING ANGLE.
∗SOLID STATE RELIABILITY.
∗CATEGORIZED FOR LUMINOUS INTENSITY.
∗**LEAD-FREE PACKAGE(ACCORDING TO ROHS)**

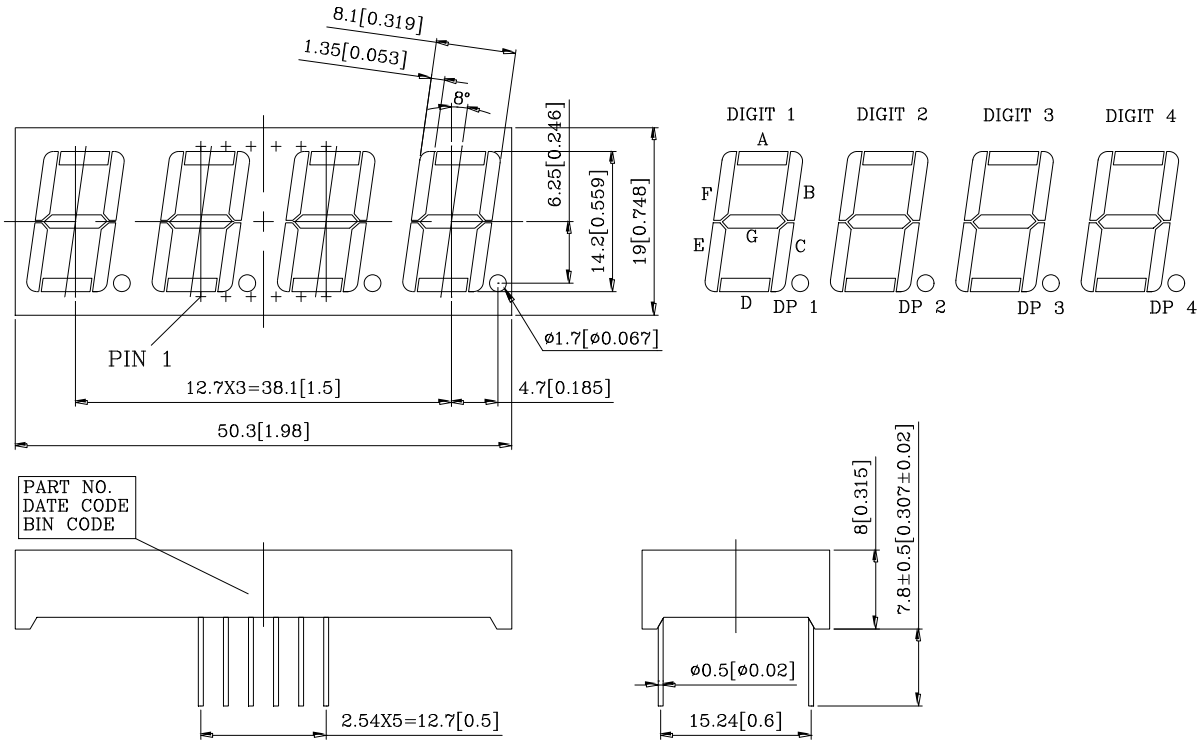
DESCRIPTION

The LTC-5623JG-J is a 0.56 inch (14.2 mm) digit height quadruple digit seven-segment display. This device utilizes AlInGap green LED chips, which are made from AlInGap on a non-transparent GaP substrate, and has a black face and green segments.

DEVICE

PART NO.	DESCRIPTION
AlInGap Green	Multiplex Common Anode
LTC-5623JG-J	Rt. Hand Decimal

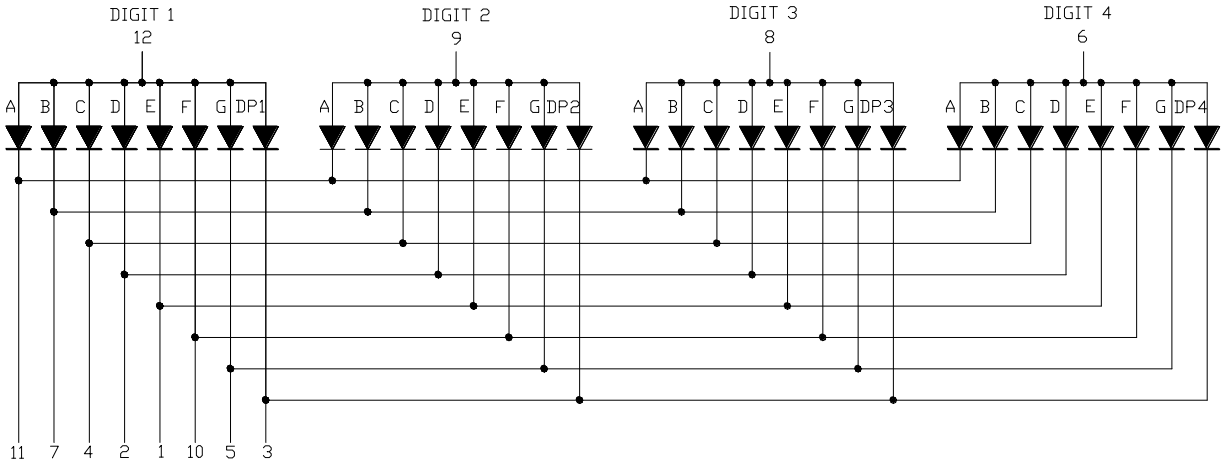
PACKAGE DIMENSIONS



NOTES: 1.All dimensions are in millimeters. Tolerances are± 0.25 mm (0.01“) unless otherwise noted.

2. Pin tip’s shift tolerance is ± 0.4 mm.

INTERNAL CIRCUIT DIAGRAM



PIN CONNECTION

NO.	CONNECTION
1	CATHODE E
2	CATHODE D
3	CATHODE D.P.
4	CATHODE C
5	CATHODE G
6	COMMON ANODE (DIGIT 4)
7	CATHODE B
8	COMMON ANODE (DIGIT 3)
9	COMMON ANODE (DIGIT 2)
10	CATHODE F
11	CATHODE A
12	COMMON ANODE (DIGIT 1)

ABSOLUTE MAXIMUM RATING AT Ta=25°C

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Segment	70	mW
Peak Forward Current Per Segment (1/10 Duty Cycle, 0.1ms Pulse Width)	60	mA
Continuous Forward Current Per Segment Derating Linear From 25℃ Per Segment	25	mA mA/℃
Reverse Voltage Per Segment	0.28	V
Operating Temperature Range	-35℃ to +105℃	
Storage Temperature Range	-35℃ to +105℃	
Solder Temperature: max 260℃ for max 3sec at 1.6mm below seating plane. or temperature of unit (during assembly) not over max. temperature rating above		

ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I_V	320	700		μcd	I_F=1mA
Peak Emission Wavelength	λp		571		nm	I_F=20mA
Spectral Line Half-Width	Δλ		15		nm	I_F=20mA
Dominant Wavelength	λd		572		nm	I_F=20mA
Forward Voltage Per Segment	V_F		2.05	2.6	V	I_F=20mA
Reverse Current Per Segment	I_R			100	μA	V_R=5V
Luminous Intensity Matching Ratio (Similar Light Area)	I_V-m			2:1		I_F=1mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

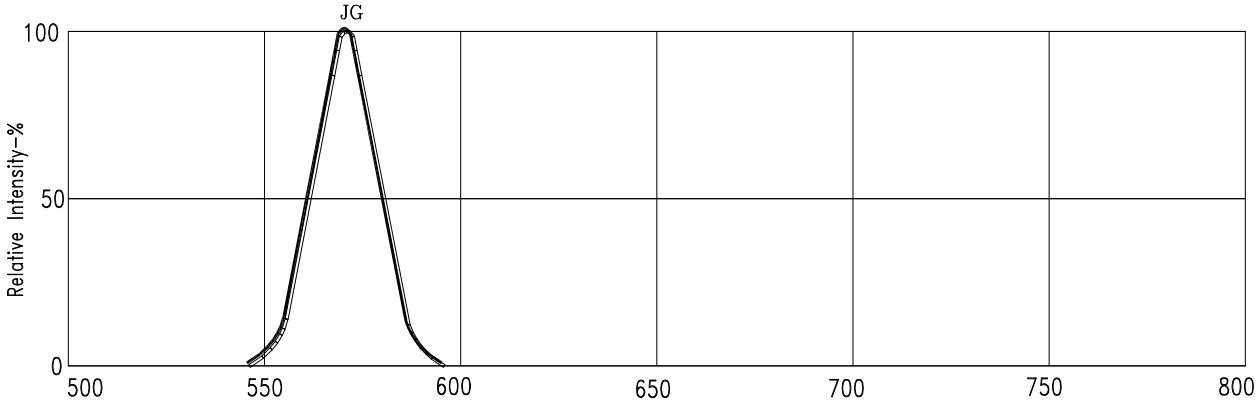


Fig1.Spectral Emission

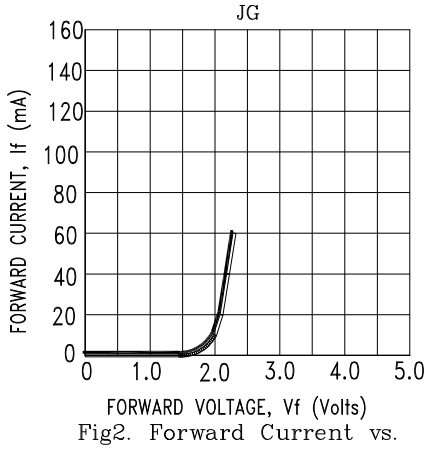


Fig2. Forward Current vs. Forward Voltage

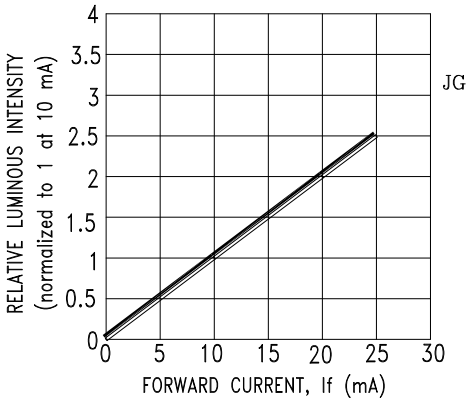


Fig3. Relative Luminous Intensity vs. DC Forward Current

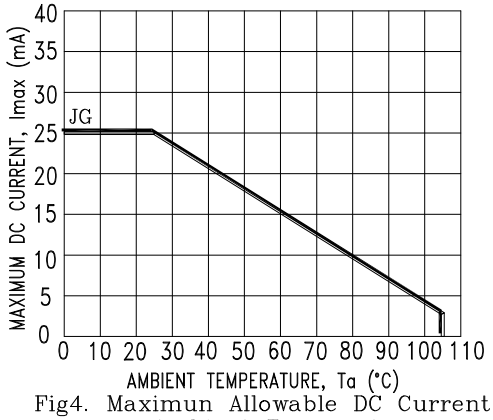


Fig4. Maximun Allowable DC Current vs. Ambient Temperature

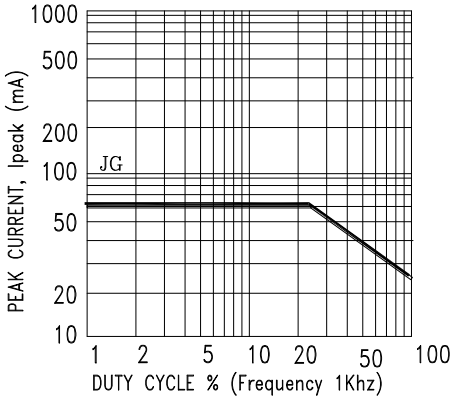


Fig5. Maximum Peak Current vs. Duty Cycle %

NOTE : JG=AlInGaP Green